

## N-CHANNEL MOS FIELD EFFECT POWER TRANSISTOR

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2SK800

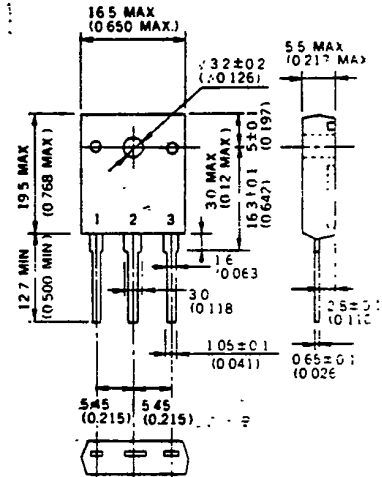
**DESCRIPTION** The 2SK800 is N-channel MOS Field Effect Power Transistor designed for converters.

**FEATURES**

- Suitable for switching power supplies, actuator controls, and pulse circuits
- Low  $R_{DS(on)}$
- No second breakdown

**ABSOLUTE MAXIMUM RATINGS****Maximum Temperatures**Storage Temperature . . . . .  $-55$  to  $+150$  °CChannel Temperature . . . . .  $150$  °C Maximum**Maximum Power Dissipation ( $T_C = 25$  °C)**

Total Power Dissipation . . . . . 120 W

**Maximum Voltages and Currents ( $T_a = 25$  °C)** $V_{DSS}$  Drain to Source Voltage . . . . . 450 V $V_{GSS}$  Gate to Source Voltage . . . . .  $\pm 20$  V $I_{D(DC)}$  Drain Current (DC) . . . . .  $\pm 18$  A $I_{D(pulse)}$  Drain Current (pulse)\* . . . . .  $\pm 60$  A\*  $PW \leq 100 \mu s$ , Duty Cycle  $\leq 2\%$ **PACKAGE DIMENSIONS**  
in millimeters (inches)

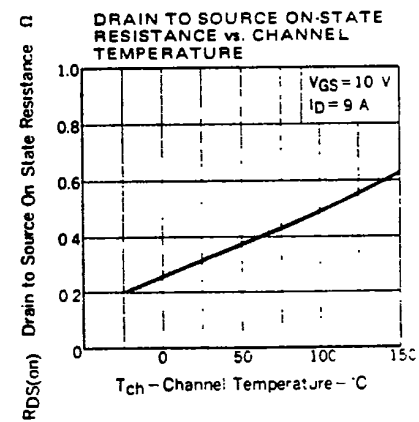
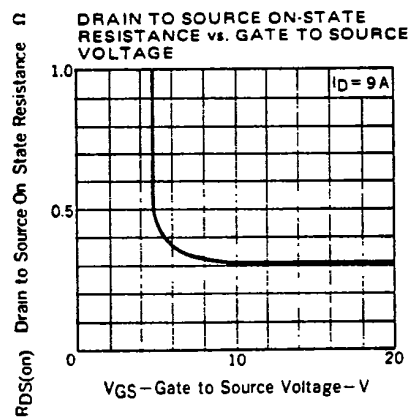
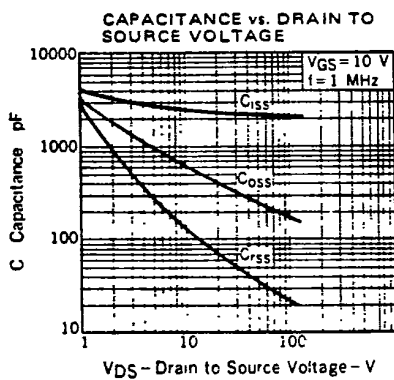
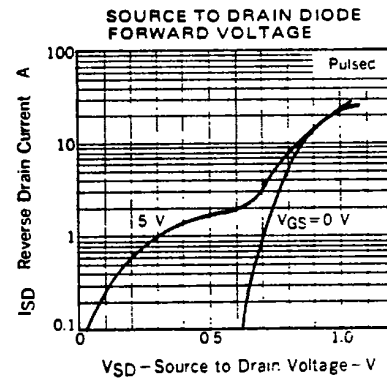
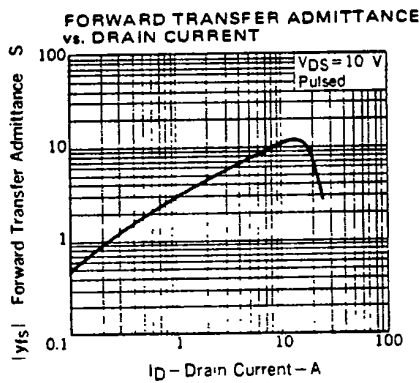
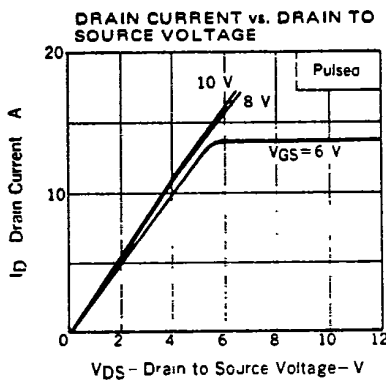
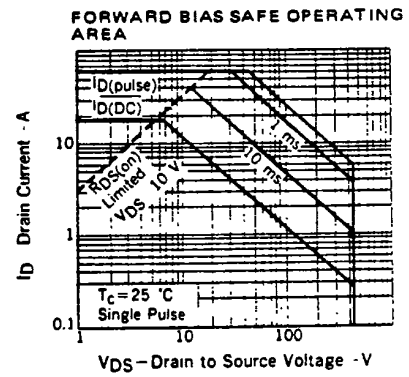
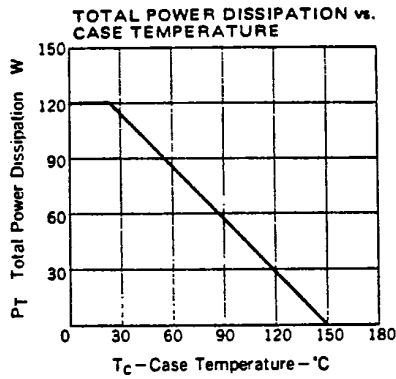
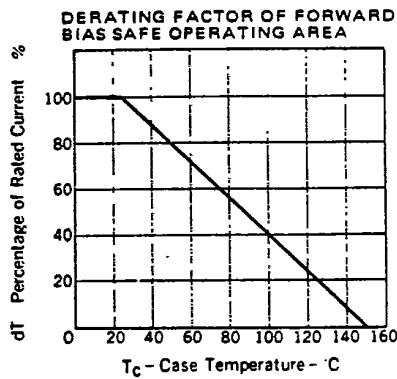
1. Gate  
2. Drain (Fin)  
3. Source

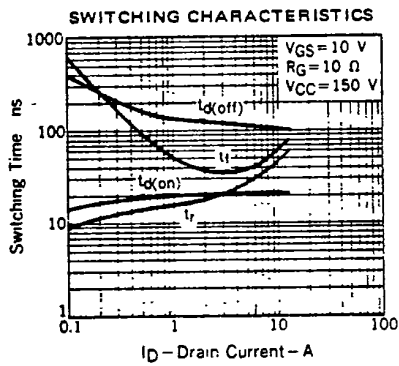
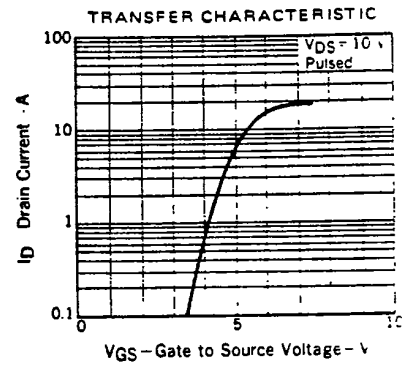
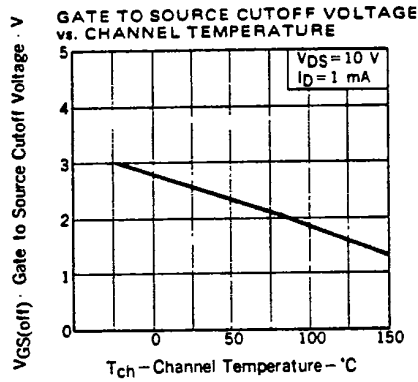
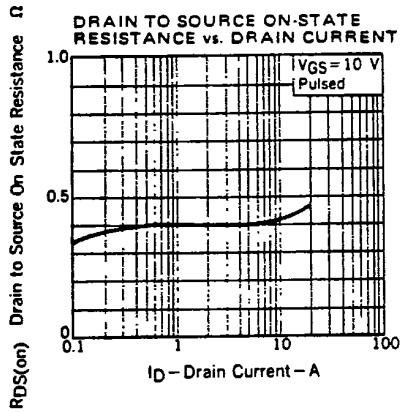
**ELECTRICAL CHARACTERISTICS ( $T_a = 25$  °C)**

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
$I_{DSS}$	Drain Leakage Current			100	$\mu A$	$V_{DS} = 450 V, V_{GS} = 0$
$I_{GSS}$	Gate to Source Leakage Current			$\pm 100$	nA	$V_{GS} = \pm 20 V, V_{DS} = 0$
$V_{GS(off)}$	Gate to Source Cutoff Voltage	1.5		3.5	V	$V_{DS} = 10 V, I_D = 1 mA$
$ y_{fs} $	Forward Transfer Admittance	8.0			S	$V_{DS} = 10 V, I_D = 9 A$
$R_{DS(on)}$	Drain to Source On-State Resistance		0.32	0.38	$\Omega$	$V_{GS} = 10 V, I_D = 9 A$
$C_{iss}$	Input Capacitance		2600		pF	
$C_{oss}$	Output Capacitance		610		pF	$V_{DS} = 10 V, V_{GS} = 0, f = 1 MHz$
$C_{rss}$	Reverse Transfer Capacitance		140		pF	
$t_{d(on)}$	Turn-On Delay Time		20		ns	
$t_r$	Rise Time		40		ns	$I_D = 9 A, V_{CC} = 150 V$
$t_{d(off)}$	Turn-Off Delay Time		120		ns	$V_{GS(on)} = 10 V$
$t_f$	Fall Time		55		ns	$R_{in} = 10 \Omega$

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TYPICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)





**SWITCHING TIME TEST CIRCUIT**

